NSN 5961-01-465-3150

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Inclosure Material:

Glass

Overall Length:

10.15 millimeters

Overall Height:

0.80 millimeters

Overall Width:

10.15 millimeters

Internal Configuration:

Junction contact

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

20.0 collector to base voltage/static/emitter open and 10.0 collector to emitter voltage/static/base open and 1.5 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

65.00 milliamperes source cutoff current

Power Rating Per Characteristic:

580.0 milliwatts small-signal input power, common-emitter outside diameter

Maximum Operating Tempurature Per Measurement Point:

-65.0 degrees celsius case and 150.0 degrees celsius case

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

4 ribbon

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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